



DMN2710UW

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C
201/	0.45Ω @ V _{GS} = 4.5V	0.9A
20V	0.6Ω @ V _{GS} = 2.5V	0.8A

Description and Applications

This MOSFET has been designed to minimize the on-state resistance (RDs(ON)) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- General Purpose Interfacing Switch
- Power Management Functions
- DC-DC Converters
- Analog Switch

20V N-CHANNEL ENHANCEMENT MODE MOSFET

Features and Benefits

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

Mechanical Data

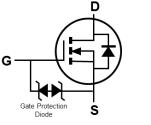
- Case: SOT323
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (e3)
- Weight: 0.027 grams (Approximate)

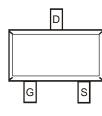




SOT323

Top View





Equivalent Circuit

Top View

Ordering Information (Note 4)

Part Number	Case	Packaging
DMN2710UW-7	SOT323	3,000/Tape & Reel
DMN2710UW-13	SOT323	10,000/Tape & Reel

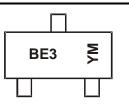
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



 $\begin{array}{l} \text{BE3} = \text{Product Type Marking Code} \\ \text{YM} = \text{Date Code Marking} \\ \hline \hline Y = \text{Year (ex: H = 2020)} \\ \text{M} = \text{Month (ex: 9 = September)} \end{array}$

Date Code Key

Notes:

	0000	0004	0000	0000	0004	0005	0000	0007	0000	0000	0000	0004
Year	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code	н	1	J	K	L	М	N	0	Р	R	S	Т
									-	_		_
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec



Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	Vdss	20	V	
Gate-Source Voltage		V _{GSS}	±6	V
Continuous Drain Current (Note 6) V_{GS} = 4.5V	ID	0.9 0.7	А	
Pulsed Drain Current (10µs Pulse, Duty Cycle=1%)	ldм	5	A	
Maximum Body Diode Forward Current (Note 5)		ls	0.6	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)		PD	0.47	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	RθJA	268	°C/W
Total Power Dissipation (Note 6)		PD	0.6	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R _{0JA}	212	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BVDSS	20	—		V	V _{GS} = 0V, I _D = 250µA
Zero Gate Voltage Drain Current @Tc = +25	°C Idss	_	—	100	nA	V _{DS} =20V, V _{GS} = 0V
Gate-Source Leakage	IGSS	_	—	±1.0	μA	$V_{GS} = \pm 4.5 V, V_{DS} = 0 V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	VGS(TH)	0.5	—	1.0	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$
			0.13	0.45		$V_{GS} = 4.5V, I_{D} = 600 \text{mA}$
Static Drain-Source On-Resistance	RDS(ON)		0.16	0.6	Ω	VGS = 2.5V, ID = 500mA
			0.22	0.75		$V_{GS} = 1.8V, I_D = 350mA$
Diode Forward Voltage	Vsd		0.7	1.2	V	VGS = 0V, IS = 150mA
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss		42	—	pF	
Output Capacitance	Coss		13	—	pF	$V_{DS} = 16V, V_{GS} = 0V$ f = 1.0MHz
Reverse Transfer Capacitance	Crss		6.5	—	pF	1 = 1.0MHZ
Total Gate Charge	Qg		0.6	—	nC	
Gate-Source Charge	Qgs		0.1		nC	$V_{GS} = 4.5V, V_{DS} = 10V,$
Gate-Drain Charge	Q _{gd}		0.1	_	nC	I _D = 250mA
Turn-On Delay Time	td(on)		4.9		ns	
Turn-On Rise Time Turn-Off Delay Time		_	3.1	_	ns	$V_{DD} = 10V, V_{GS} = 4.5V,$
			386		ns	$R_L = 47\Omega, R_g = 10\Omega$
Turn-Off Fall Time	tF	_	174	—	ns	$I_D = 200 \text{mA}$
Reverse Recovery Time	t _{RR}	_	88		ns	I _F = 1.0A, di/dt = 100A/µs
Reverse Recovery Charge	QRR	_	29	_	nC	IF = 1.0A, di/dt = 100A/µs

Notes:

Device mounted on FR-4 substrate PC board, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.



DMN2710UW

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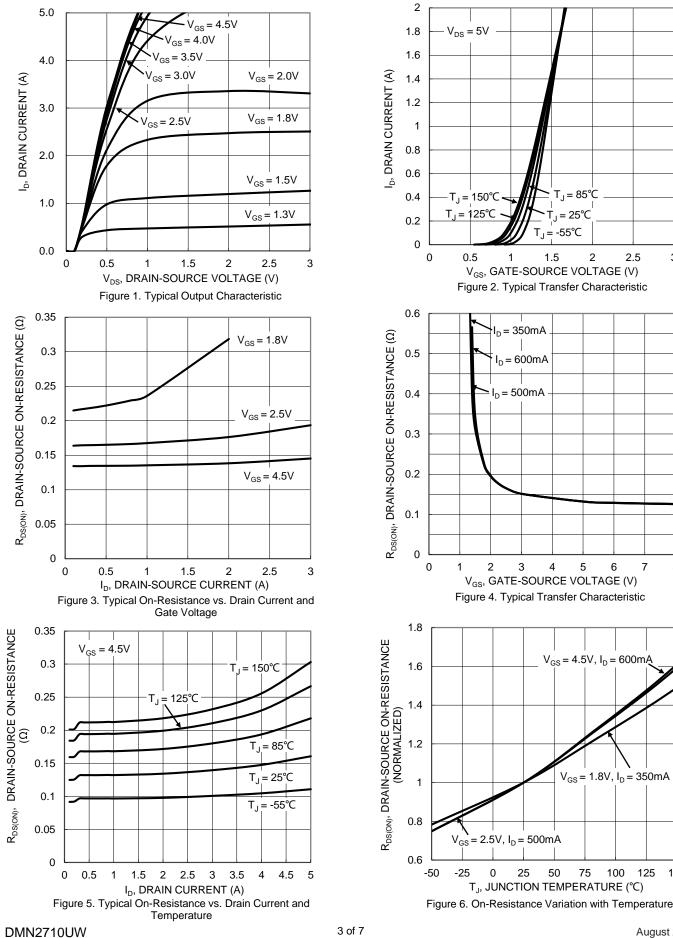
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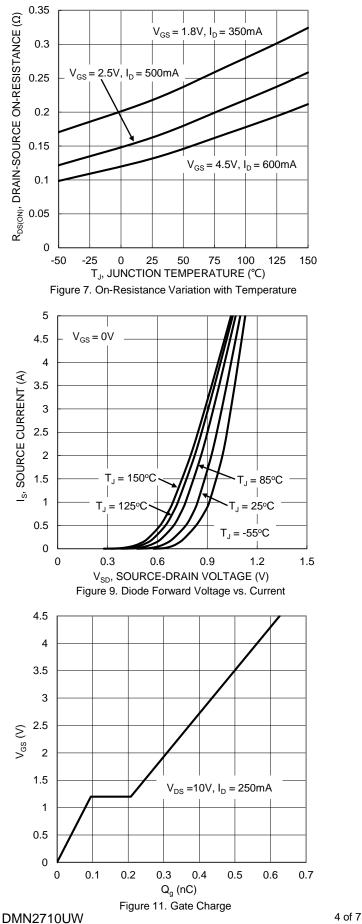
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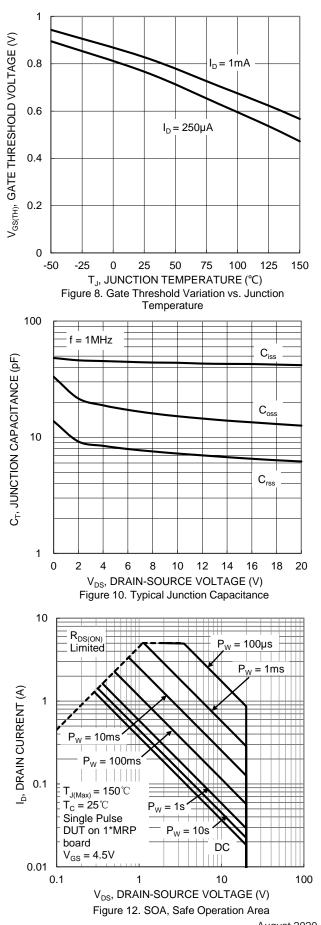
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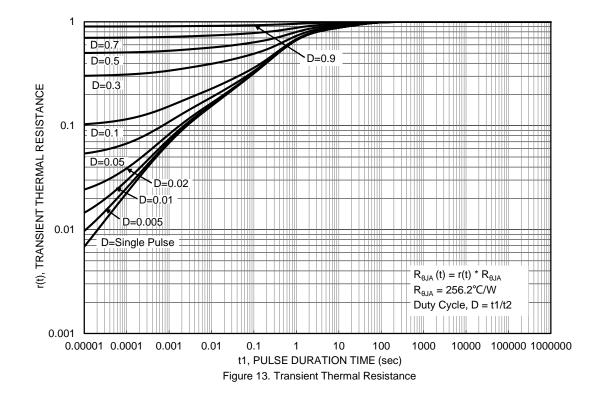


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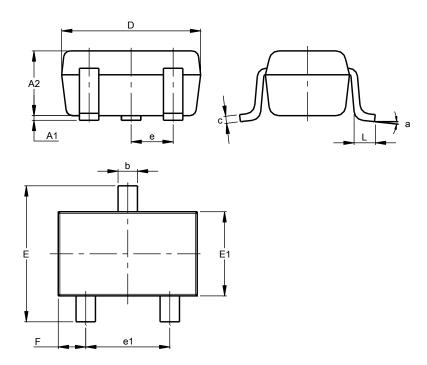




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

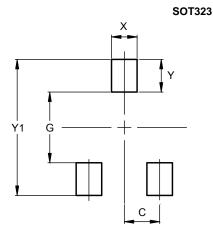




SOT323								
Dim	Min	Max	Тур					
A1	0.00	0.10	0.05					
A2	0.90	1.00	0.95					
b	0.25	0.40	0.30					
C	0.10	0.18	0.11					
D	1.80	2.20	2.15					
Е	2.00	2.20	2.10					
E1	1.15	1.35	1.30					
e	C).650 B	SC					
e1	1.20	1.40	1.30					
F	0.375	0.475	0.425					
L	0.25	0.40	0.30					
а	0°	8°						
All	Dimen	sions i	in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	0.650
G	1.300
Х	0.470
Y	0.600
Y1	2.500

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